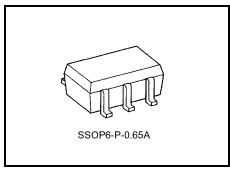
TOSHIBA CMOS Digital Integrated Circuit Silicon Monolithic

TC7PA53FU

2-Channel Multiplexer/Demultiplexer

Features

- Ultra-low on resistance: R_{ON} = 21 Ω (max) at V_{CC} = 3.6 V
- Operating voltage range: V_{CC (opr.)} = 1.8 to 3.6 V
- 3.6 V Tolerant inputs.

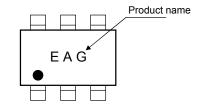


Weight: 0.0068 g (typ.)

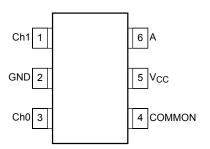
Maximum Ratings (Ta = 25°C)

Characteristics		Symbol	Rating	Unit	
Power supply voltage		V _{CC}	-0.5 to 4.6	V	
DC input voltage	9	V _{IN}	-0.5 to 4.6	V	
Switch I/O voltage	Switch I/O voltage		-0.5 to V_{CC} + 0.5	V	
Clamp diode	Control input block	luz	-50	mA	
current	Switch block	lik	±50	IIIA	
Switch through of	Switch through current		100	mA	
Power dissipation		P_{D}	200	mW	
DC V _{CC} /ground current		Icc	±100	mA	
Storage tempera	ature	T _{stg}	-65 to 150	°C	

Marking



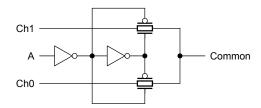
Pin Assignment (top view)



Truth Table

Input	On Channel
Α	On Chambe
L	Ch0
Н	Ch1

System Diagram



Recommended Operating Conditions

Characteristics	Symbol	Rating	Unit
Power supply voltage	V _{CC}	1.8 to 3.6	V
Control input voltage	V _{IN}	0 to 3.6	V
Switch I/O voltage	V _S	0 to V _{CC}	V
Operating temperature	T _{opr}	-40 to 85	°C
Control input rise and fall time	d _t /d _V	0 to 10	ns/V

Electrical Characteristics

DC Electrical Characteristics ($Ta = -40 \text{ to } 85^{\circ}\text{C}$)

Characteristics		Symbol Test Condition			Min	Max	Unit
		Symbol	rest obligation	V _{CC} (V)	IVIIII	IVIAX	Offic
	High level	V _{IH}		1.8	V _{CC} × 0.75		V
Input voltage	nigii level		_	2.3 to 3.6	V _{CC} × 0.75		
input voitage	Low level	V _{IL}		1.8	ı	V _{CC} × 0.25	V
	Low level	VIL.	_	2.3 to 3.6		V _{CC} × 0.25	
			$V_{IN} = 0 V$, $I_O = 24 \text{ mA}$	3.6		19	
			$V_{IN} = 1.9 \text{ V}, I_O = -24 \text{ mA}$	3.6		18	Ω
		R _{ON}	$V_{IN} = 3.6 \text{ V}, I_O = -24 \text{ mA}$	3.6	_	16	
On resistance			$V_{IN} = 0 \text{ V}, I_O = 24 \text{ mA}$	3.0		21	
$V_{I/O} = V_{CC}$ or GND	1		$V_{IN} = 3 \text{ V}, I_O = -24 \text{ mA}$	3.0	_	17	
V /0 = VCC 01 014E	,		$V_{IN} = 0 \text{ V}, I_{O} = 18 \text{ mA}$	2.3	_	25	
			$V_{IN} = 2.3 \text{ V}, I_O = -18 \text{ mA}$	2.3	_	20	
			V _{IN} = 0 V, I _O = 6 mA	1.8	_	32	
			V _{IN} = 1.8 V, I _O = -6 mA	1.8	_	26	
			$0 < V_{IN} < 3.6 \text{ V}, I_O = 24 \text{ mA}$	3.6	_	21	
On resistance	On resistance		$0 < V_{IN} < 3 V, I_O = 24 \text{ mA}$	3.0	_	23	
$V_{I/O} = V_{CC}$ to GND		R _{ON}	$0 < V_{IN} < 2.3 \text{ V}, I_O = 18 \text{ mA}$	2.3	_	42	Ω
			$0 < V_{IN} < 1.8 \text{ V}, I_O = 6 \text{ mA}$	1.8	_	140	
Control input leakage current		I _{IN}	V _{IN} = 0 to 3.6 V	3.6	_	±5.0	μА
Switch I/O leakage current		I _{SZ}	V _{IN} = 0 to 3.6 V	3.6	_	10.0	μА
Quiescent supply of	current	Icc	V _{IN} = V _{CC} or GND	3.6	_	20.0	
Increase in I _{CC} per	Increase in I _{CC} per Input		V _{IH} = 3 V	3.6	_	750	μА



AC Characteristics (Ta = -40 to 85°C, input $t_r = t_f = 2.0$ ns, $C_L = 30$ pF, $R_L = 500 \Omega$)

Characteristics	Symbol	Test Condition	V _{CC} (V)	Min	Max	Unit
	^t pZL ^t pZH	Figure 1,2	1.8	_	9	
Output enable time			2.5 ± 0.2	_	7	ns
			3.3 ± 0.3	_	5	
Output disable time	t _{pLZ} t _{pHZ}	Figure 1,2	1.8	_	9	
			2.5 ± 0.2	_	7	ns
			3.3 ± 0.3	_	5	

The propagation delay time is defined by test condition as follows: (calculating condition: see Figure 3)

 $Propagation \ delay \ time \ (reference) = - \left(\ C_{OS} + C_{L} \ \right) \cdot \\ \left(R_{DRIVE+} R_{ON} \right) \cdot \\ ln \left(\left(\ (\ V_{OH} - V_{OL} \) - V_{M} \right) / \left(\ V_{OH} - V_{OL} \) \right)$

 R_{DRIVE} = Output impedance of front circuit V_{M} = Arbitrary output threshold voltage

Example of calculation:

Propagation delay time (reference) = - (15 + 15) \cdot (0 + 21) \cdot In (((3.6 - 0) – 3.6 \cdot 50%)/(3.6 – 0)) = approximately 0.4 ns

Calculating condition:

 V_{CC} = 3.6V , C_L = 15pF , R_{DRIVE} = 0 Ω (ideal signal source) , V_M = 50% Input signal to switch = Digital signal ("H" revel voltage=3.6V , "L" revel voltage = 0V)

Capacitive Characteristics (Ta = 25°C)

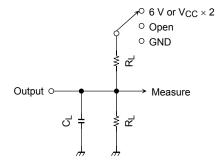
Characteristics	Symbol	Test Condition		Тур.	Unit
Characteristics	Symbol	rest Condition	V _{CC} (V)		
Input capacitance	C _{IN}	_	1.8, 2.5, 3.3	3	pF
Common Terminal Capacitance	C _{IS}	_	1.8, 2.5, 3.3	6	pF
Switch Terminal Capacitance	Cos	_	1.8, 2.5, 3.3	15	pF
Feed Through Capacitance	C _{IOS}	_	1.8, 2.5, 3.3	0.3	pF
Power dissipation capacitance	C _{PD}	$f_{IN} = 10 \text{ MHz}$ (Note 1) 1.8, 2.5, 3.3	5.5	pF

Note 1: C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load. Average operating current is given as:

4

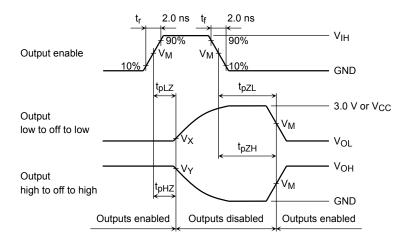
ICC (opr.) = CPD·VCC·fIN + ICC

Figure 1 AC Test Circuit



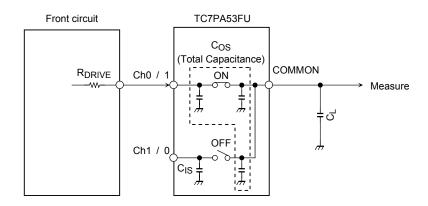
Characteristics	Switch		
	6 V at $V_{CC} = 3.3 \pm 0.3 \text{ V}$		
t_{pLZ}, t_{pZL}	V 2	at V_{CC} = 2.5 \pm 0.2 V	
	V _{CC} × 2	at $V_{CC} = 1.8 \text{ V}$	
t _{pHZ} , t _{pZH}	GND		

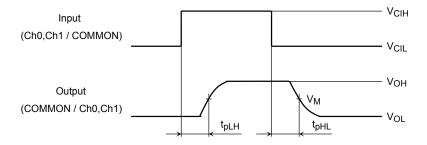
Figure 2 AC Waveforms t_{pLZ} , t_{pHZ} , t_{pZL} , t_{pZH}



Symbol		V _{CC}	
Syllibol	$3.3\pm0.3~\textrm{V}$	$2.5\pm0.2\textrm{V}$	1.8 V
V _{IH}	2.7 V	V _{CC}	V _{CC}
V _M	1.5 V	V _{CC/2}	V _{CC/2}
VX	V _{OL} + 0.3 V	V _{OL} + 0.15 V	V _{OL} + 0.15 V
VY	V _{OH} – 0.3 V	V _{OH} – 0.15 V	V _{OH} – 0.15 V

Figure 3 Calculating condition for propagation delay time t_{pLH}, t_{pHL}





 R_{DRIVE} = Output impedance of front circuit V_{M} = Arbitrary output threshold voltage V_{CIH} = "H" revel input voltage to switch

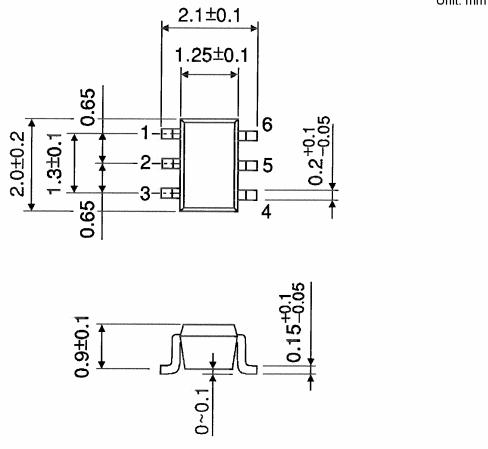
V_{CIL} = "L" revel input voltage to switch

Symbol	Vcc			
Syllibol	3.3 ± 0.3 V	2.5 ± 0.2 V	1.8 V	
V _M	arbitrary	arbitrary	arbitrary	

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Package Dimensions

SSOP6-P-0.65A Unit: mm



Weight: 0.0068 g (typ.)

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